Unitized Semiconductor Devices - Page 1 of 1



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Matal	
Metal	
Overall Length:	
0.250 inches	
Terminal Length:	
0.490 inches	
Overall Diameter:	
0.352 inches	
Joint Electronic Device Engineering Council/jedec/case Outline Desig	nation:
To-76	
Component Name And Quantity:	
2 transistor	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.200 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts Per Characteristic:	
30.0 breakdown voltage, drain-to-source, with all other terminals short-cir	cuited to source all transistor and 6.0 gate to source threshold
voltage all transistor	
Current Rating Per Characteristic:	
200.00 milliamperes zero-gate-voltage drain current all transistor	
Power Rating Per Characteristic:	
600.0 milliwatts total device dissipation all transistor	
Maximum Operating Tempurature Per Measurement Point:	
175.0 degrees celsius junction	
Terminal Type And Quantity:	
8 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
-	
Demilitarization:	
No	
Fiig:	
A110a0	